Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	6590	SOI.clm. or (silicon adj2 insulat$3).clm.	US-PGPUB; USPAT	OR	OFF	2005/04/05 07:20
L2	2824	1 and buried	US-PGPUB; USPAT	OR	OFF	2005/04/05 07:21
L3	1117	1 and buried.clm.	US-PGPUB; USPAT	OR	OFF	2005/04/05 07:47
L4	1114	3 and insulat$3	US-PGPUB; USPAT	OR	OFF	2005/04/05 07:22
L5	894	4 and (gate or electrode)	US-PGPUB; USPAT	OR	OFF	2005/04/05 07:22
L6	138	5 and boundary	US-PGPUB; USPAT	OR	OFF	2005/04/05 07:22
L7	118	6 and thickness	US-PGPUB; USPAT	OR	OFF	2005/04/05 07:22
L8	124	6 and thick$4	US-PGPUB; USPAT	OR	OFF	2005/04/05 07:26
L9	74	8 and (box.clm. or (insulat$3 near3 buried).clm. or (oxide near3 buried).clm.)	US-PGPUB; USPAT	OR	OFF	2005/04/05 07:27
L10	879	2 and ((buried near3 (oxide or insulat$3)).clm. or box.clm.)	US-PGPUB; USPAT	OR	OFF	2005/04/05 07:48
L11	553	10 and (second near8 (insulat$3 or oxide or box))	US-PGPUB; USPAT	OR	OFF	2005/04/05 07:49
L12	324	10 and (second near8 ((buried near4 insulat$3) or (buried near3 oxide) or box))	US-PGPUB; USPAT	OR	OFF	2005/04/05 07:51
L13	13	12 and (non adj SOI)	US-PGPUB; USPAT	OR	OFF	2005/04/05 07:58
L14	9	12 and (partial adj SOI)	US-PGPUB; USPAT	OR	OFF	2005/04/05 07:58